

# SILICON TRANSISTOR 2SA1871

# PNP SILICON TRIPLE DIFFUSED TRANSISTOR FOR HIGH-SPEED HIGH-VOLTAGE SWITCHING

The 2SA1871 is a transistor developed for high-speed high-voltage switching and is ideal for use in switching elements such as switching regulators and DC/DC converters.

#### **FEATURES**

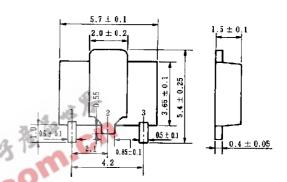
- New package with dimensions in between those of small signal and power signal package
- · High voltage
- · Fast switching speed
- · Complementary transistor with 2SC4942

#### **QUALITY GRADES**

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1: Emitter
- 2: Collector
- 3: Base

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-600	V
Collector to emitter voltage	VCEO		-600	V
Emitter to base voltage	V <sub>EBO</sub>		-7.0	V
Collector current (DC)	Ic(DC)		-1.0	Α
Collector current (pulse)	IC(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 %	-2.0	Α
Total power dissipation	Рт	$7.5~\text{cm}^2 \times 0.7~\text{mm}$ ceramic board used	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	T <sub>stg</sub>		-55 to +150	°C

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



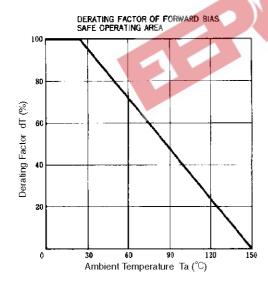
## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

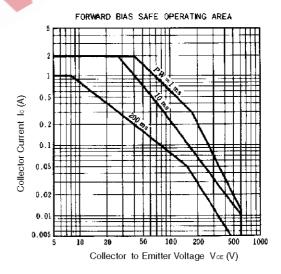
Paran	neter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit	
Collector cutof	f current	Ісво	V <sub>CB</sub> = -600 V, I <sub>E</sub> = 0					-10	μΑ	
Emitter cutoff	current	Ієво	V <sub>EB</sub> = -7.0 V, I <sub>C</sub> = 0					-10	μΑ	
DC current gai	in	h <sub>FE1</sub>	VcE = -5.0 V, Ic = -0.1 A		30	60	120	_		
DC current gai	in	h <sub>FE2</sub>	Vce = -5.0 V, Ic = -0.5 A		5	20		_		
Collector satur	ation voltage	V <sub>CE(sat)</sub>	Ic = -300 mA, I <sub>B</sub> = -60 mA			-0.3	-1.0	V		
Base saturatio	n voltage	V <sub>BE(sat)</sub>	Ic = -300 mA, I <sub>B</sub> = -60 mA			-0.85	-1.2	V		
Gain bandwidt	h product	f⊤	VcE = -10 V, IE = 50 mA			30		MHz		
Output capacit	tance	Cob	VcB = -10 V, IE = 0, f = 1.0 MHz			40		pF		
Turn-on time		ton	Ic = -0.5 A, Vcc = -250 V			0.1	0.5	μs		
Storage time		<b>t</b> stg	$I_{B1} = -I_{B2} = -0.1 \text{ A},$				3.5	5.0	μs	
Fall time		tf	$R_L = 500 \Omega$ ,			0.1	0.5	μs		
hfe CLASSI	FICATION					水水	ngto-			
Marking	GA1		GA2 GA3							
h <sub>FE1</sub>	30 to 60		40 to 80 60 to 120		カー	M.C.				
hre CLASSIFICATION           Marking         GA1         GA2         GA3           hre1         30 to 60         40 to 80         60 to 120           TYPICAL CHARACTERISTICS (Ta = 25°C)           DERATING FACTOR OF FORWARD BIAS										

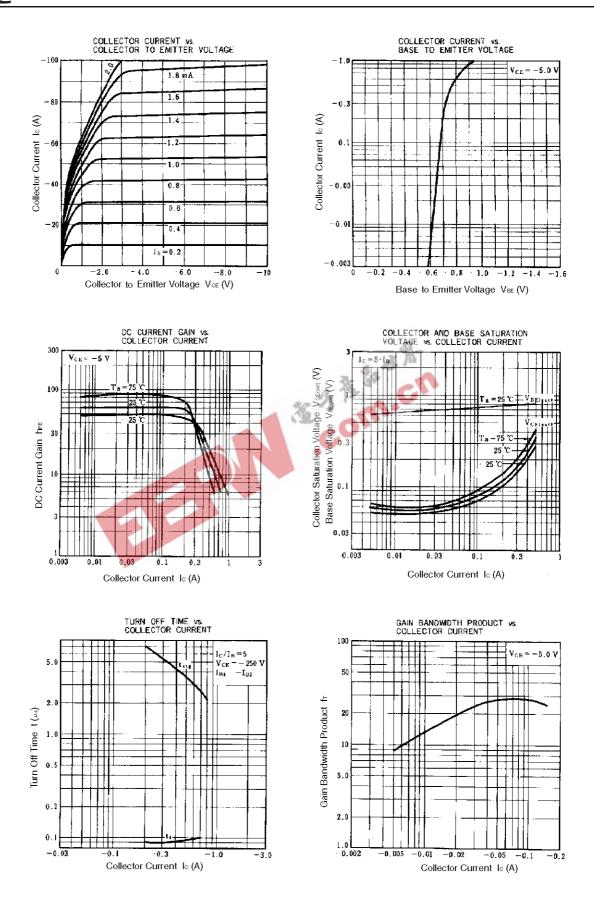
#### **hfe CLASSIFICATION**

Marking	GA1	GA2	GA3
h <sub>FE1</sub>	30 to 60	40 to 80	60 to 120

## TYPICAL CHARACTERISTICS (Ta = 25°C)

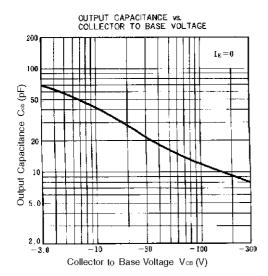






Data Sheet D16144EJ1V0DS

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